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RESPONSE UNDER 37 CFR 1.116
EX parte PROCEDURE EXAMINING
GROUP 2811

201540US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF:

TOMOHIRO YAMASHITA ET AL.

: GROUP ART UNIT: 2811

SERIAL NO.: 09/754,325

:

FILED: JANUARY 5, 2001

: EXAMINER: NADAV, O.

FOR: SEMICONDUCTOR DEVICE

:

AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

In response to the Official Action dated December 10, 2002, please amend the above-identified patent application as follows:

IN THE CLAIMS

Please amend Claims 1 and 13 as shown in the attached marked-up copy to read as follows:

FAX RECEIVED

Subj Ctr on B

1. (Twice Amended) A semiconductor device comprising:
a semiconductor substrate;
a first well of a prescribed conductivity type at which a first active element is provided, said first well being selectively formed in a surface of said semiconductor substrate;
a second well of the same conductivity type as said prescribed conductivity type at which a second active element is provided, said second well being selectively formed in said surface of said semiconductor substrate;

MAR 11 2003

TECHNOLOGY CENTER 2800